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DEPARTMENT OF PHYSICS AND PHYSICAL OCEANOGRAPHY MEMORIAL UNIVERSITY OF NEWFOUNDLAND

Final Exam Winter 2006 Physics 3410

April 15, 2006 Time: 2 hours

INSTRUCTIONS:

- 1. Attempt ALL questions (1-6) in Part 1. Attempt 1 out of the 2 questions (7,8) in Part 2. Marks assigned to each question are indicated in the margin.
- 2. Write you answers in the space provided and use the backs of sheets as needed. An extra blank page is provided at the end for Part 2 if needed.
- 3. Use ink. Do not erase or use whiteout. Indicate deletion by a line drawn neatly through unwanted material.
- 4. If what anything is not clear, ask. Don't panic.

POTENTIALLY USEFUL EQUATIONS:

$$\wp(s) = \frac{e^{-E(s)/kT}}{7}$$
 Boltzmann Distribution (Canonical Distribution)

$$\wp(s) = \frac{e^{-[E(s) - \mu N(s)]/kT}}{Z}$$
 Grand Canonical Distribution

$$Z = \sum_{s} e^{-\beta E(s)}$$
 Partition function

$$\mathcal{Z} = \sum_{s} e^{-\beta[E(s) - \mu N(s)]}$$
 Grand Partition Function

$$Z_1 = \sum_{s} e^{-E(s)/kT}$$
 Single particle partition function

$$\overline{E} = -\frac{1}{Z} \frac{\partial Z}{\partial \beta}$$

$$l_{\rm Q} = \frac{h}{\sqrt{2\pi mkT}}$$

power per unit area = σT^4

$$\sum_{n=0}^{\infty} x^n = (1-x)^{-1}$$
 for $x < 1$. Infinite geometric series

$$N_A = 6.02 \times 10^{23}$$

$$h = 6.626 \times 10^{-34} \,\text{J} \cdot \text{s} = 4.136 \times 10^{-15} \,\text{eV} \cdot \text{s}$$

$$k = 1.381 \times 10^{-23} \text{ J/K} = 8.617 \times 10^{-5} \text{ eV/K}$$

$$\beta = (kT)^{-1}$$

$$e^x = 1 + x + \frac{x^2}{2} + \cdots$$

$$\cosh(x) = \frac{1}{2} \left(e^x + e^{-x} \right)$$

$$(1+x)^{-1} \approx 1-x+\cdots \text{ for } |x| << 1$$

$$\sinh(x) = \frac{1}{2} \left(e^x - e^{-x} \right)$$

$$\ln(1+x) \approx x - \frac{x^2}{2} + \cdots$$
 for $|x| << 1$

$$\tanh(x) = \frac{\sinh(x)}{\cosh(x)}$$

$$N! \approx N^N e^{-N} \sqrt{2\pi N}$$

$$\ln N! \approx N \ln N - N$$

1	2	3	4	5	6	7	8	Total

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PART 1: Do questions 1, 2, 3, 4, 5 and 6

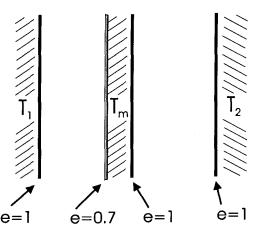
- [10] 1. (a) What is meant by the fundamental assumption of statistical mechanics?
 - (b) Consider a small system in thermal equilibrium with a large reservoir. Comment briefly on the relationship between the probability that the small system is in a particular microstate and the multiplicity of the reservoir.
 - (c) The nucleus of the ¹⁴N atom is a spin-1 particle. The allowed values of the z component of the ¹⁴N nucleus are $\mu_z = -\mu_{14\rm N}$, $\mu_z = 0$, and $\mu_z = +\mu_{14\rm N}$ where $\mu_{14\rm N} = 2.04 \times 10^{-27}$ J/T. The energy of a magnetic moment in a field of magnitude B is $E = -\mu_z B$.
 - (i) Find an expression for the partition function of a ¹⁴N nucleus in a magnetic field of magnitude B and evaluate it for T = 298 K and B = 9.4 T.
 - (ii) Calculate the average magnetic moment, $\overline{\mu}_z$, for ¹⁴N nuclei at $T = 298 \,\mathrm{K}$ in a magnetic field of magnitude $B = 9.4 \,\mathrm{T}$

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- [5] 2. (a) Briefly discuss how the characteristic length scale for fluctuations in a parameter like density or magnetization might change as a system approaches a critical point. Comment on how this observation suggests that the critical point can be identified with the fixed point in a recursion relation for coupling obtained from a renormalization group calculation.
 - (b) The mean field model predicts that below the Curie temperature, the temperature dependence of the magnetization goes like $M \propto (T_C T)^{1/2}$. Experimentally, the behaviour of 3-dimensional ferromagnets is found to be closer to $M \propto (T_C T)^{1/3}$. The difference is presumably because the mean field approximation neglects some elements of the behaviour of real systems near a critical point. Identify one such behaviour that is neglected by the mean field approximation.

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[5] 3. Two large parallel surfaces, 1 and 2, are at temperatures $T_1 = 298 \, \mathrm{K}$ and $T_2 = 77 \, \mathrm{K}$ respectively. Both surfaces have emissivity e = 1.0. A thin metal sheet is inserted into the space between these surfaces. The emissivity of the surface of this sheet facing surface 1 is e = 0.70. The emissivity of the surface of this sheet facing surface 2 is e = 1.0. What is the equilibrium temperature, T_m , of the middle sheet?



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- [5] 4. The Debye density of phonon states has the form $g_{\text{Debye}}(\varepsilon) = \frac{12\pi V}{h^3 c_s^3} \varepsilon^2$ for $\varepsilon < kT_{\text{D}}$ and $g_{\text{Debye}}(\varepsilon) = 0$ for $\varepsilon > kT_{\text{D}}$. The Debye model approximates the observed heat capacity of a solid well for $T << T_{\text{D}}$ and for $T >> T_{\text{D}}$.
 - (a) What aspect(s) of the Debye model account(s) for the agreement with observations at low temperature? Briefly comment on why this is a good approximation for low temperature behaviour.
 - (b) What aspect(s) of the Debye model account(s) for the agreement with observations at high temperature?

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- [10] 5. (a) The Planck Distribution, $\overline{n}_{\rm Pl} = \frac{1}{e^{\varepsilon/kT}-1}$, has the same form as the Bose-Einstein distribution would have for particles with chemical potential $\mu = 0$. To what kinds of particles is the Planck Distribution applied and why might $\mu = 0$ be reasonable for such particles.
 - (b) The allowed wavelengths for photon modes in a $L \times L \times L$ box are $\lambda = \frac{2L}{\sqrt{n_x^2 + n_y^2 + n_z^2}}$ where n_x , n_y , and n_z are positive integers. The energy of a photon of wavelength λ is $\varepsilon = \frac{hc}{\lambda}$. Show that the photon density of states is given by $g(\varepsilon) = \frac{8\pi L^3}{h^3c^3} \varepsilon^2$.

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[10] 6. (a) For an Ising model with no external field, the internal energy in a domain is $U = -\varepsilon \sum_{\substack{\text{nearest} \\ \text{neighbours}}} s_i s_j$ where $s_i = \pm 1$ denotes whether dipoles are parallel or antiparallel

to the z axis. Briefly describe what is meant by a mean field approximation and show that such an approximation yields $\bar{s} = \tanh(\beta \varepsilon n \bar{s})$ where n is the number of nearest-neighbours.

(b) Using $\lim_{x\to 0} \tanh(x) = x$ and the result in part (b), find an expression for the temperature, T_C , at which the system first displays a spontaneous non-zero magnetization upon cooling. It may be helpful to sketch a graph that represents your solution to the transcendental equation for \overline{s} .

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PART 2: Do one (1) out of the two questions (7 or 8) in Part 2. (an extra blank page is available at the end if needed)

- [15] 7. (a) Consider a single particle boson state (energy = ε) that can be occupied by an integer number of bosons. Derive the grand partition function for this state by treating the state as a "system" and the other single particle states as a "reservoir" of particles with chemical potential μ .
 - (b) Use your result from (a) to derive the Bose-Einstein distribution function $\overline{n}_{BE} = \frac{1}{e^{(\varepsilon \mu)/kT} 1}$ from the definition $\overline{n} = \sum_{n} n \, \wp(n)$ for the average number of particles in a particular single particle state. Hint: it may be helpful to note $ne^{-nx} = -\frac{\partial e^{-nx}}{\partial x}.$
 - (c) Show that for temperatures low enough to give a macroscopic occupation of the lowest single particle state (with energy ε_0), the number of particles in the ground state is $N_0 = \frac{kT}{\varepsilon_0 \mu}$. What does this imply regarding the low temperature limit of the chemical potential for bosons.
 - (d) Sketch the temperature dependence of the chemical potential for a gas of weakly interacting bosons. Indicate the Bose-Einstein condensation temperature on your graph.

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- [15] 8. Consider a gas of N spin-1/2 fermions confined to a one dimensional space of length L so that the allowed single particle state energies are $\varepsilon = \frac{h^2 n_x^2}{8mL^2}$.
 - (a) Derive an expression for the density of states, $g(\varepsilon)$ for this system of particles.
 - (b) Based on your result for part (b), do you expect the chemical potential to increase, decrease, or stay constant as temperature is raised slightly from T = 0 K? Briefly justify your answer.
 - (c) The chemical potential must satisfy $N=\int\limits_0^\infty g(\varepsilon)\overline{n}_{FD}d\varepsilon$ where $\overline{n}_{FD}=\frac{1}{e^{(\varepsilon-\mu)/kT}+1}.$ Obtain an expression for the chemical potential at $T>>\varepsilon_F/k$ in terms of N,L,kT, and the quantum length l_Q . You can assume that the chemical potential is large and negative for $T>>\varepsilon_F/k$ and you may find it useful

to note that $\int_{0}^{\infty} \frac{e^{-x}}{\sqrt{x}} dx = \sqrt{\pi} .$

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Extra page for part 2: